

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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HIGH CURRENT, 3-PHASE FULL WAVE BRIDGE ASSEMBLY

SET111403 SET111419 SET111412 SET111404 SET111411

January 16, 1998

TEL:805-498-2111 FAX:805-498-3804 WEB:http://www.semtech.com

HIGH CURRENT, HIGH DENSITY, THREE PHASE FULL WAVE BRIDGE RECTIFIER.

- Low thermal impedance
- Small size and low weight
- High current applications
- Isolated for direct heatsink mounting
- High surge ratings

QUICK REFERENCE DATA

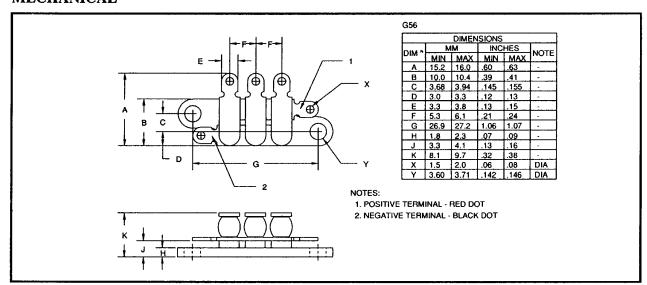
- $V_R = 150V 1000V$
- $I_0 = 45A$
- $t_{rr} = 30nS 2\mu S$
- I_{FSM} ≥ 150A

ABSOLUTE MAXIMUM RATINGS

Device Type	Working Reverse Voltage (V _{RWM})	Average Rectified Current (IF(AV)) @ Tmb			1 Cycle Surge I _{FSM} t _p = 8.3mS		Repetitive Surge (I _{FRM})	Operating & Storage Temperature Range
		@ 55°C	100°C	125°C	@ 25 ℃	@ 100°C	@ 25 ℃	(T _{OP}) (T _{STG})
	Volts	Amps	Amps	Amps	Amps	Amps	Amps	°C
SET111403	1000	45	33	24	150	100	25	-55 to +175
SET111419	1000	30	24	18	150	80	15	-55 to +175
SET111412	600	45	33	24	150	100	25	-55 to +175
SET111404	400	45	33	24	150	80	25	-55 to +175
SET111411	150	45	30	21	175	175	24	-55 to +150
I		1			ı			

 $R_{\theta jc} = 0.5^{\circ} C/W$

MECHANICAL

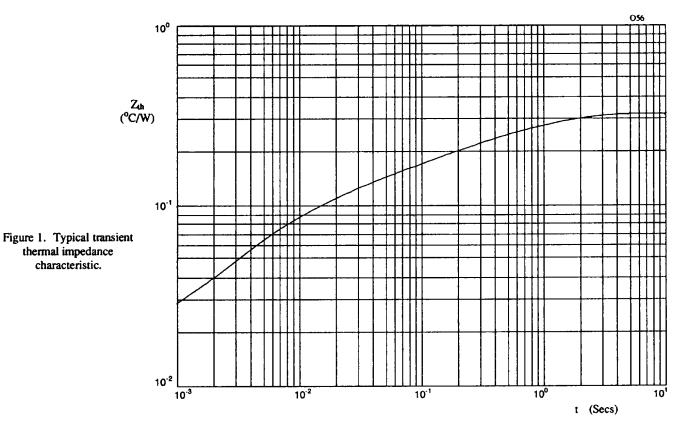


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ELECTRICAL CHARACTERISTICS

Device Type		n Leakage R @ VRWM	Maximum Forward Voltage V _F @ 9A @ 25°C	
1	1, - 20 0	1, - 100 C		t _{rr}
	μΑ	μΑ	Volts	nS
SET111403	3.0	60	1.2	2000
SET111419	3.0	<i>7</i> 5	2.2	150
SET111412	3.0	60	1.2	2000
SET111404	3.0	60	1.5	150
SET111411	30.0	1.5mA	1.1	30

¹ Measured on discrete devices prior to assembly



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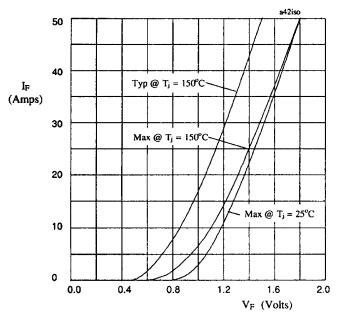


Figure 2. Forward voltage drop per leg as a function of forward current for SET111403 & SET111412.

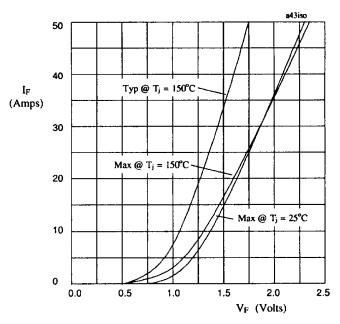


Figure 3. Forward voltage drop per leg as a function of forward current for SET111404.

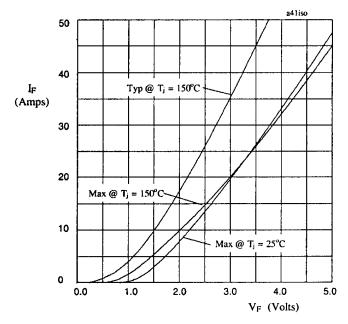


Figure 4. Forward voltage drop per leg as a function of forward current for SET111419.

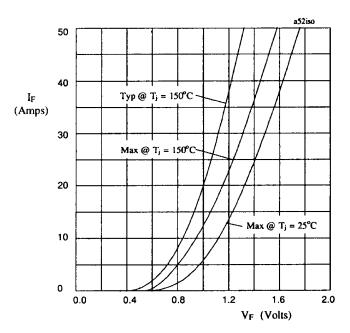


Figure 5. Forward voltage drop per leg as a function of forward current for SET111411.

HIGH CURRENT, 3-PHASE FULL WAVE BRIDGE ASSEMBLY

SET111403 SET111419 SET111412 SET111404 SET111411

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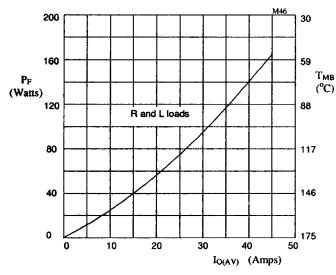


Figure 6. Forward power dissipation and maximum allowable mounting base temperature as a function of output current for sinusoidal operation, for SET111403 and SET111412.

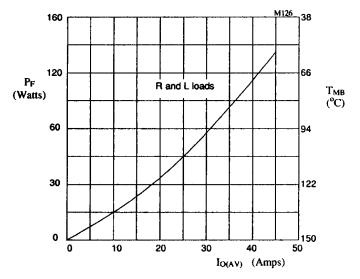


Figure 8. Forward power dissipation and maximum allowable mounting base temperature as a function of output current for sinusoidal operation, for SET111411.

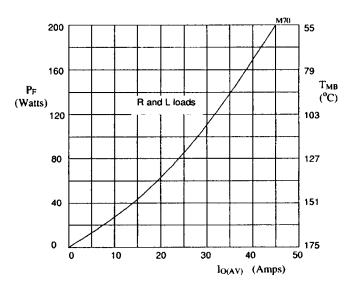


Figure 7. Forward power dissipation and maximum allowable mounting base temperature as a function of output current for sinusoidal operation, for SET111404.